

MAC4DCM, MAC4DCN

Preferred Device

Triacs

Silicon Bidirectional Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

- Small Size Surface Mount DPAK Package
- Passivated Die for Reliability and Uniformity
- Blocking Voltage to 800 V
- On-State Current Rating of 4.0 Amperes RMS at 108°C
- High Immunity to dv/dt — 500 V/ μs at 125°C
- High Immunity to di/dt — 6.0 A/ms at 125°C
- Device Marking: Device Type with “M” truncated, e.g., MAC4DCM: AC4DCM, Date Code

MAXIMUM RATINGS ($T_J = 25^\circ C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage ⁽¹⁾ ($T_J = -40$ to $125^\circ C$, Sine Wave, 50 to 60 Hz, Gate Open) MAC4DCM MAC4DCN	V_{DRM} , V_{RRM}	600 800	Volts
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, $T_C = 108^\circ C$)	$I_T(RMS)$	4.0	Amps
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, $T_J = 125^\circ C$)	I_{TSM}	40	Amps
Circuit Fusing Consideration ($t = 8.3$ msec)	I^2t	6.6	A ² sec
Peak Gate Power (Pulse Width ≤ 10 μs , $T_C = 108^\circ C$)	P_{GM}	0.5	Watt
Average Gate Power ($t = 8.3$ msec, $T_C = 108^\circ C$)	$P_{G(AV)}$	0.1	Watt
Peak Gate Current (Pulse Width ≤ 10 μs , $T_C = 108^\circ C$)	I_{GM}	0.5	Amp
Peak Gate Voltage (Pulse Width ≤ 10 μs , $T_C = 108^\circ C$)	V_{GM}	5.0	Volts
Operating Junction Temperature Range	T_J	-40 to 125	$^\circ C$
Storage Temperature Range	T_{stg}	-40 to 150	$^\circ C$

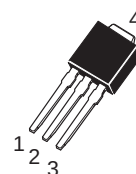
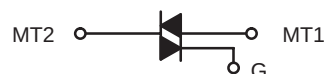
(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.



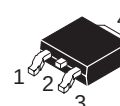
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TRIACS 4.0 AMPERES RMS 600 thru 800 VOLTS



D-PAK
CASE 369
STYLE 6



D-PAK
CASE 369A
STYLE 6

PIN ASSIGNMENT

	PIN ASSIGNMENT
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

ORDERING INFORMATION

Device	Package	Shipping
MAC4DCMT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)
MAC4DCM-1	DPAK 369	75 Units/Rail
MAC4DCNT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)
MAC4DCN-1	DPAK 369	75 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

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THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance — Junction to Case — Junction to Ambient — Junction to Ambient ⁽¹⁾	R _{θJC} R _{θJA} R _{θJA}	3.5 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes ⁽²⁾	T _L	260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Peak Repetitive Blocking Current (V _D = Rated V _{DRM} , V _{RRM} ; Gate Open)	I _{DRM} , I _{RRM}	— —	— —	0.01 2.0	mA
T _J = 25°C T _J = 125°C					

ON CHARACTERISTICS

Peak On-State Voltage ⁽³⁾ (I _{TM} = ±6.0 A)	V _{TM}	—	1.3	1.6	Volts
Gate Trigger Current (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	I _{GT}	8.0 8.0 8.0	12 18 22	35 35 35	mA
Gate Trigger Voltage (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	V _{GT}	0.5 0.5 0.5	0.8 0.8 0.8	1.3 1.3 1.3	Volts
Gate Non-Trigger Voltage (Continuous dc) (V _D = 12 V, R _L = 100 Ω) MT2(+), G(+); MT2(+), G(–); MT2(–), G(–) T _J = 125°C	V _{GD}	0.2	0.4	—	Volts
Holding Current (V _D = 12 V, Gate Open, Initiating Current = ±200 mA)	I _H	6.0	22	35	mA
Latching Current (V _D = 12 V, I _G = 35 mA) MT2(+), G(+) MT2(+), G(–) MT2(–), G(–)	I _L	— — —	30 50 20	60 80 60	mA

DYNAMIC CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Unit
Rate of Change of Commutating Current (V _D = 400 V, I _{TM} = 4.0 A, Commutating dv/dt = 18 V/μsec, Gate Open, T _J = 125°C, f = 250 Hz, CL = 5.0 μF, LL = 20 mH, No Snubber) See Figure 16	di/dt(c)	6.0	8.4	—	A/ms
Critical Rate of Rise of Off-State Voltage (V _D = 0.67 X Rated V _{DRM} , Exponential Waveform, Gate Open, T _J = 125°C)	dv/dt	500	1700	—	V/μs

(1) Surface mounted on minimum recommended pad size.

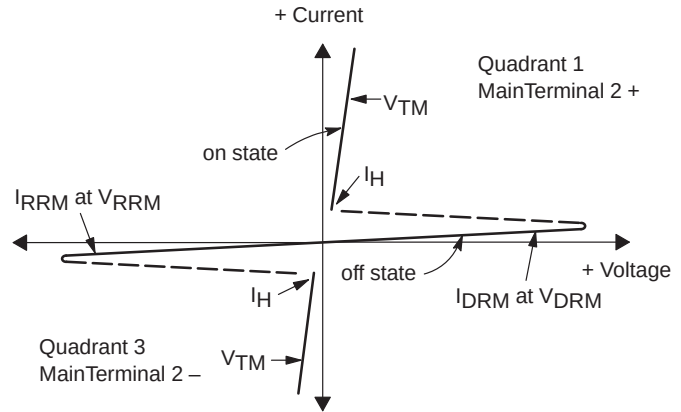
(2) 1/8" from case for 10 seconds.

(3) Pulse Test: Pulse Width ≤ 2.0 msec, Duty Cycle ≤ 2%.

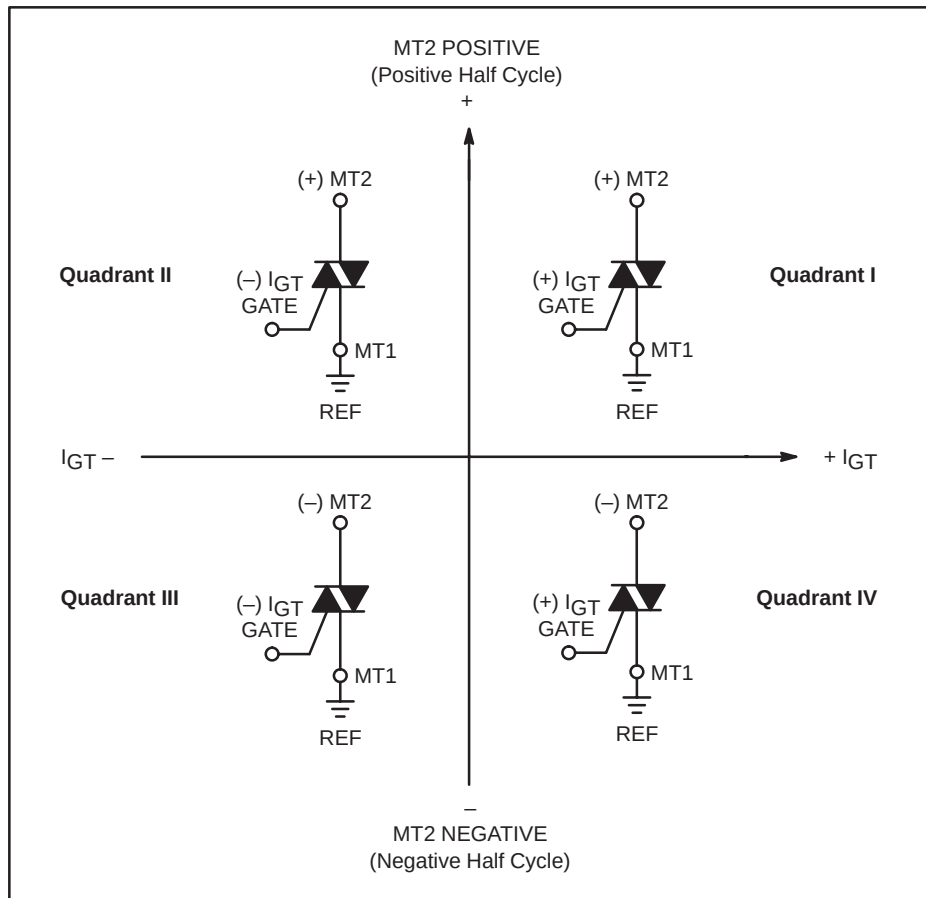
MAC4DCM, MAC4DCN

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.
With in-phase signals (using standard AC lines) quadrants I and III are used.

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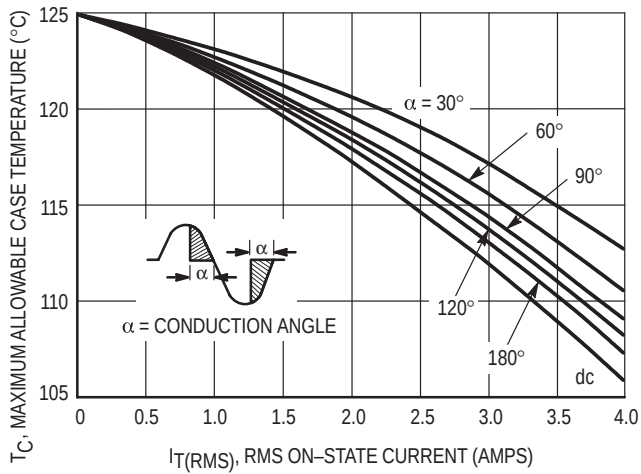


Figure 1. RMS Current Derating

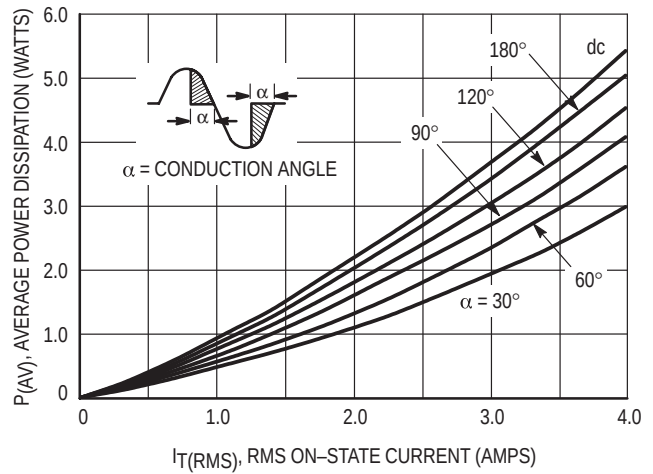


Figure 2. On-State Power Dissipation

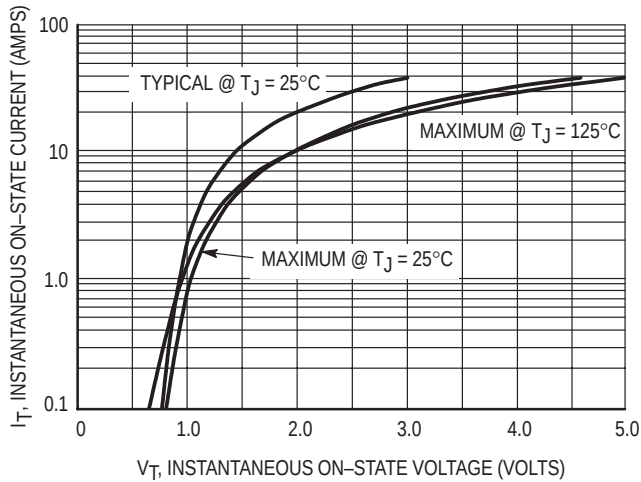


Figure 3. On-State Characteristics

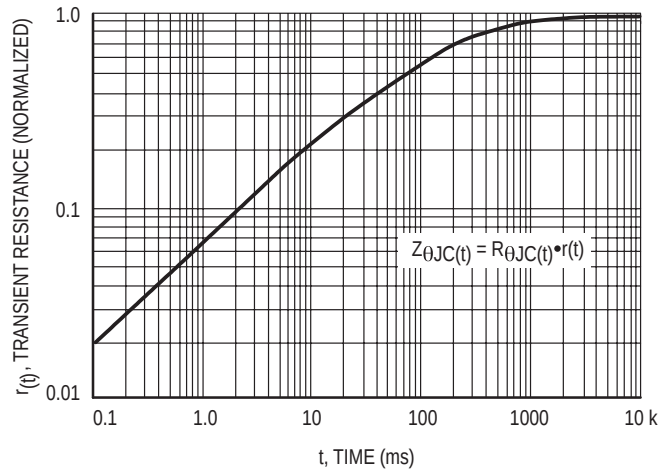


Figure 4. Transient Thermal Response

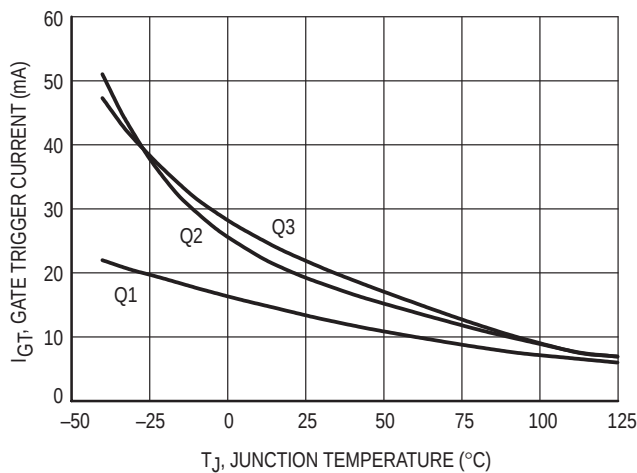


Figure 5. Typical Gate Trigger Current versus Junction Temperature

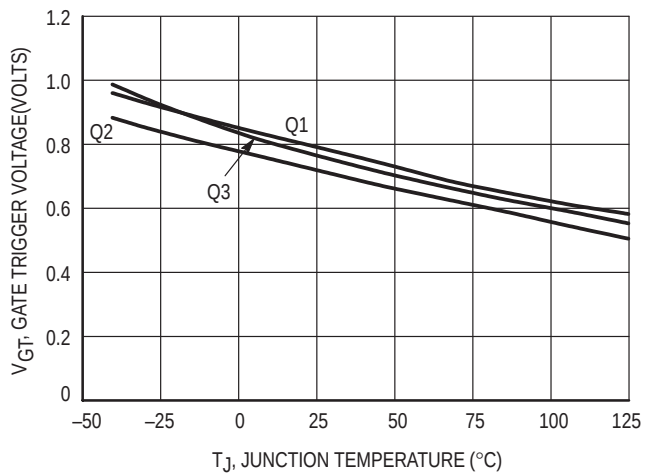


Figure 6. Typical Gate Trigger Voltage versus Junction Temperature

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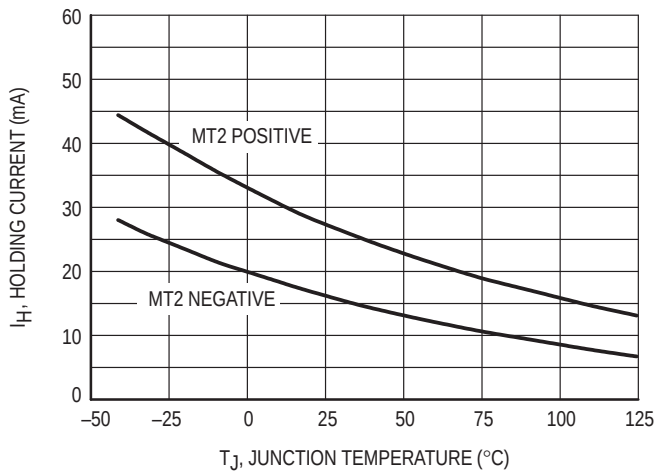


Figure 7. Typical Holding Current versus Junction Temperature

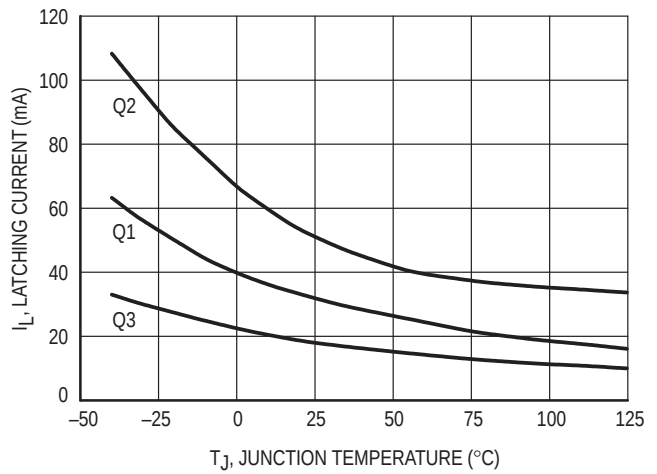


Figure 8. Typical Latching Current versus Junction Temperature

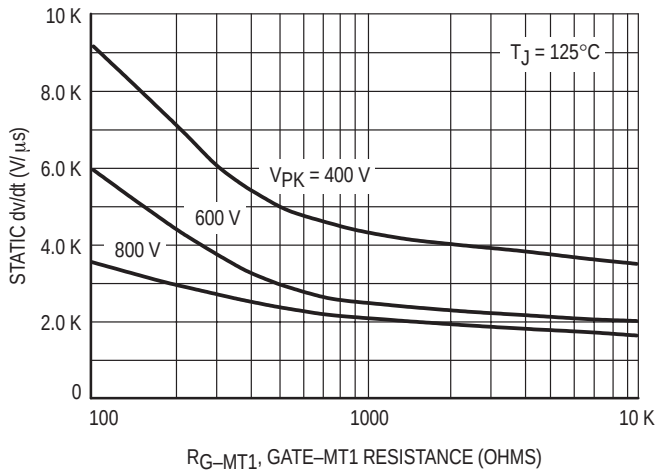


Figure 9. Exponential Static dv/dt versus Gate-MT1 Resistance, MT2(+)

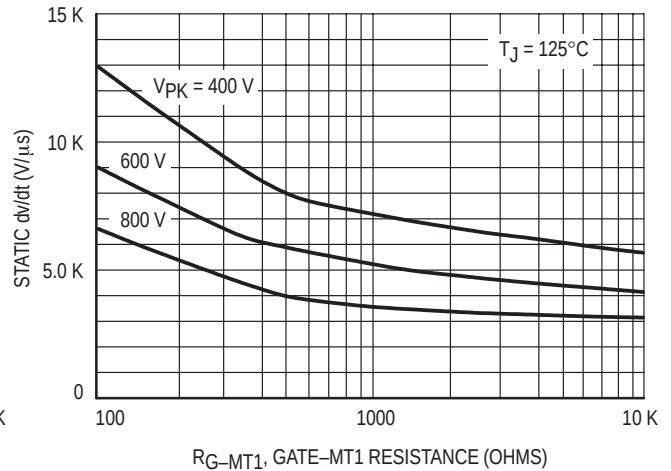


Figure 10. Exponential Static dv/dt versus Gate-MT1 Resistance, MT2(-)

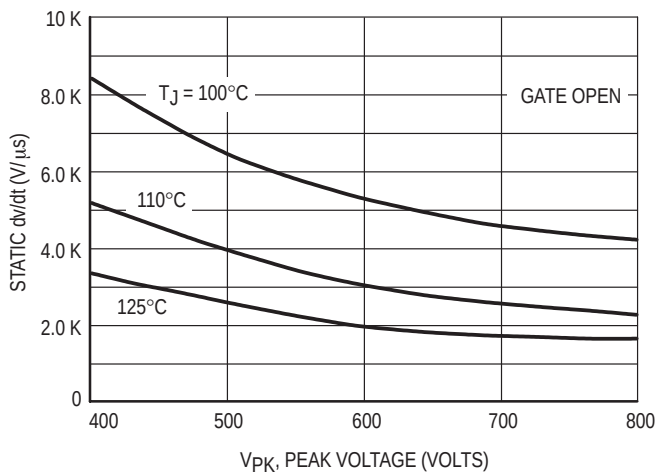


Figure 11. Exponential Static dv/dt versus Peak Voltage, MT2(+)

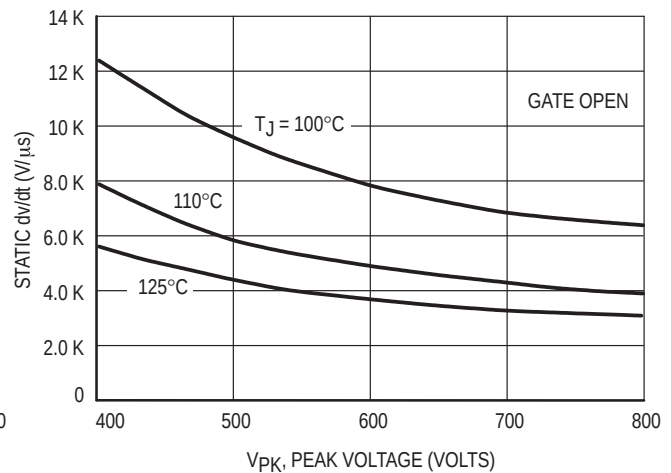


Figure 12. Exponential Static dv/dt versus Peak Voltage, MT2(-)

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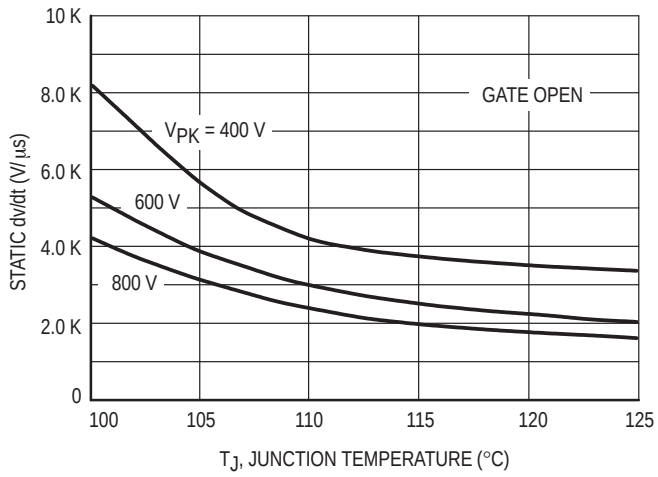


Figure 13. Typical Exponential Static dv/dt versus Junction Temperature, MT2(+)

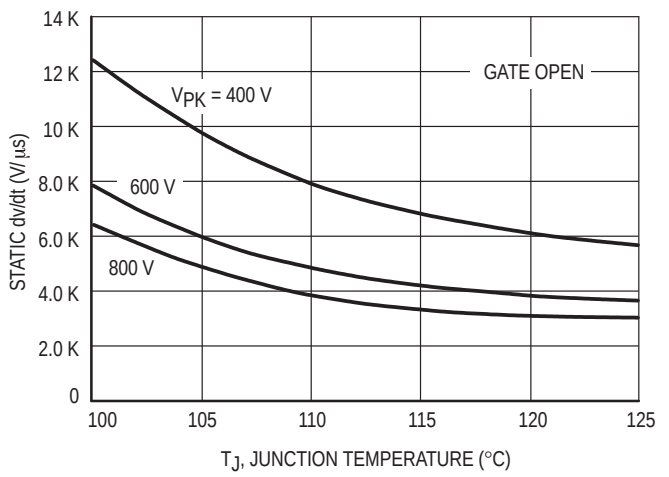


Figure 14. Typical Exponential Static dv/dt versus Junction Temperature, MT2(-)

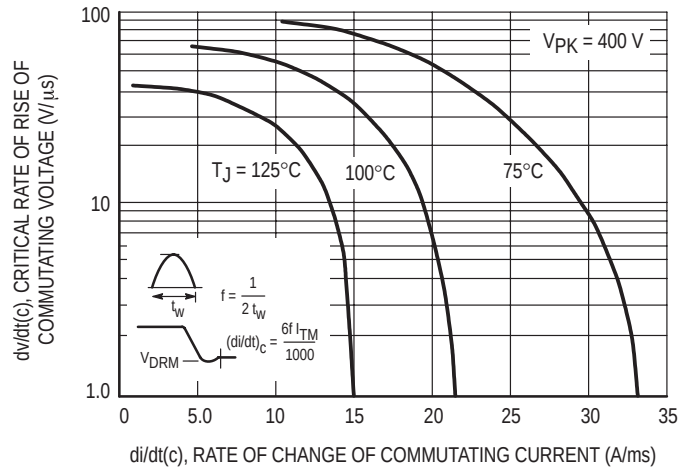
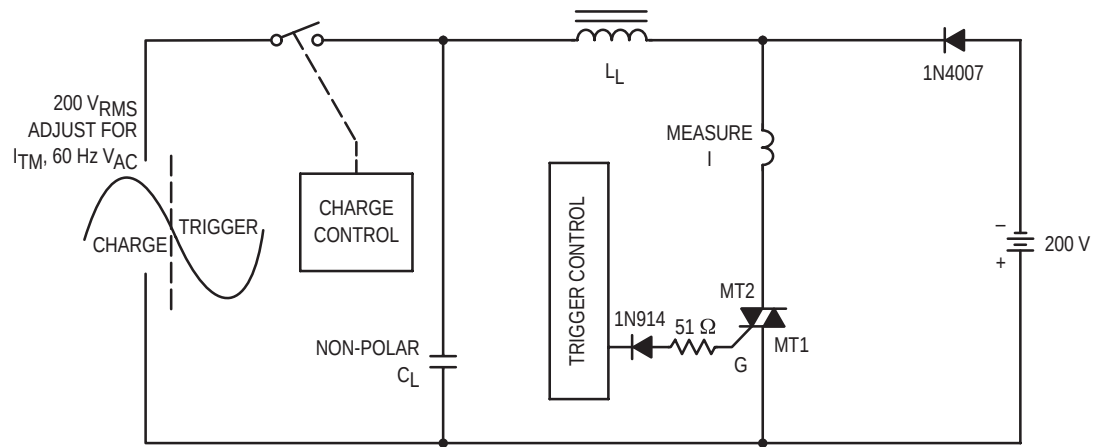


Figure 15. Critical Rate of Rise of Commutating Voltage

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Note: Component values are for verification of rated $(di/dt)_c$. See AN1048 for additional information.

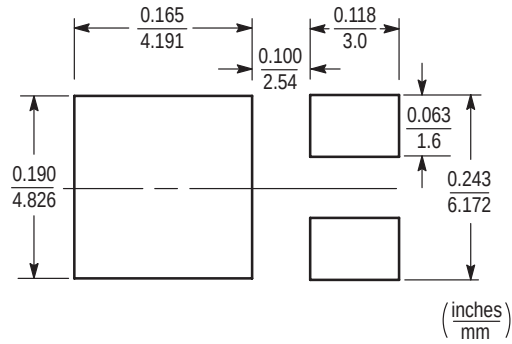
Figure 16. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current $(di/dt)_c$

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MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.

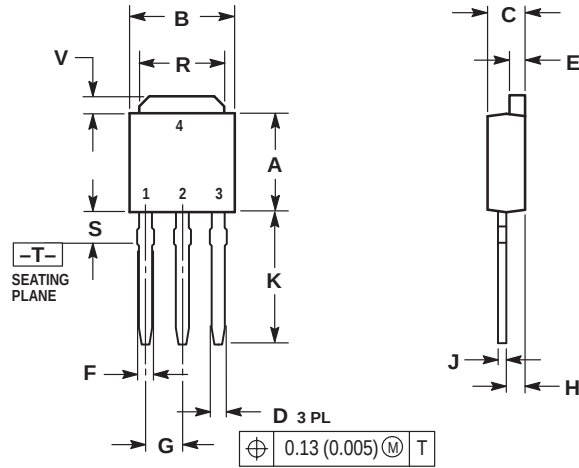


DPAK

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PACKAGE DIMENSIONS

D-PAK CASE 369-07 ISSUE L

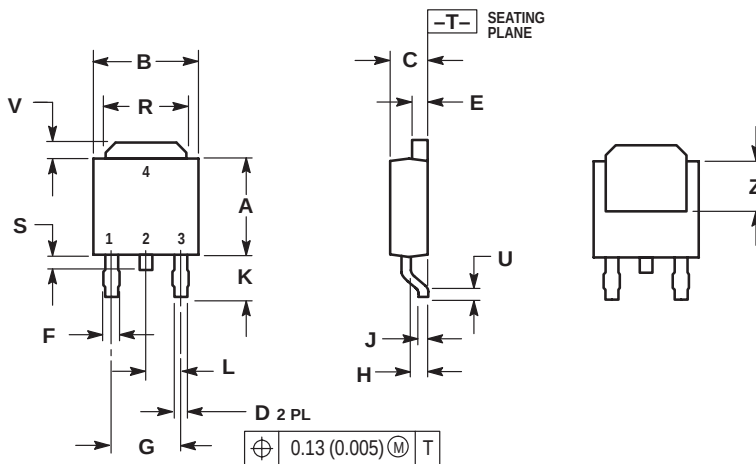


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.250	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.090 BSC		2.29 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.175	0.215	4.45	5.46
S	0.050	0.090	1.27	2.28
V	0.030	0.050	0.77	1.27

STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

D-PAK CASE 369A-13 ISSUE Z



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.250	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020	—	0.51	—
V	0.030	0.050	0.77	1.27
Z	0.138	—	3.51	—

STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

Notes

Notes

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